

Welcome to [E-XFL.COM](https://www.e-xfl.com)

## Understanding [Embedded - FPGAs \(Field Programmable Gate Array\)](#)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

## Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

### Details

Product Status	Active
Number of LABs/CLBs	6000
Number of Logic Elements/Cells	24000
Total RAM Bits	1032192
Number of I/O	197
Number of Gates	-
Voltage - Supply	1.045V ~ 1.155V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	381-FBGA
Supplier Device Package	381-CABGA (17x17)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/lattice-semiconductor/lfe5um-25f-7bg381c">https://www.e-xfl.com/product-detail/lattice-semiconductor/lfe5um-25f-7bg381c</a>

## Copyright Notice

Copyright © 2014-2018 Lattice Semiconductor Corporation. All rights reserved. The contents of these materials contain proprietary and confidential information (including trade secrets, copyright, and other Intellectual Property interests) of Lattice Semiconductor Corporation and/or its affiliates. All rights are reserved. You are permitted to use this document and any information contained therein expressly and only for bona fide non-commercial evaluation of products and/or services from Lattice Semiconductor Corporation or its affiliates; and only in connection with your bona fide consideration of purchase or license of products or services from Lattice Semiconductor Corporation or its affiliates, and only in accordance with the terms and conditions stipulated. Contents, (in whole or in part) may not be reproduced, downloaded, disseminated, published, or transferred in any form or by any means, except with the prior written permission of Lattice Semiconductor Corporation and/or its affiliates. Copyright infringement is a violation of federal law subject to criminal and civil penalties. You have no right to copy, modify, create derivative works of, transfer, sublicense, publicly display, distribute or otherwise make these materials available, in whole or in part, to any third party. You are not permitted to reverse engineer, disassemble, or decompile any device or object code provided herewith. Lattice Semiconductor Corporation reserves the right to revoke these permissions and require the destruction or return of any and all Lattice Semiconductor Corporation proprietary materials and/or data.

## Patents

The subject matter described herein may contain one or more inventions claimed in patents or patents pending owned by Lattice Semiconductor Corporation and/or its affiliates.

## Trademark Acknowledgment

Lattice Semiconductor Corporation®, the Lattice Semiconductor logo, Silicon Image®, the Silicon Image logo, Instaport®, the Instaport logo, InstaPrevue®, Simplay®, Simplay HD®, the Simplay HD logo, Simplay Labs™, the Simplay Labs logo, the SiBEAM Snap™, the SiBEAM Snap logo, UltraGig™, the UltraGig logo are trademarks or registered trademarks of Lattice Semiconductor Corporation in the United States and/or other countries. HDMI® and the HDMI logo with High-Definition Multimedia Interface are trademarks or registered trademarks of, and are used under license from, HDMI Licensing, LLC. in the United States or other countries. MHL® and the MHL logo with Mobile High-Definition Link are trademarks or registered trademarks of, and are used under license from, MHL, LLC. in the United States and/or other countries. WirelessHD®, the WirelessHD logo, WiHD® and the WiHD logo are trademarks, registered trademarks or service marks of SiBeam, Inc. in the United States or other countries.

HDMI Licensing, LLC; MHL, LLC; Simplay Labs, LLC; and SiBeam, Inc. are wholly owned subsidiaries of Lattice Semiconductor Corporation.

All other trademarks and registered trademarks are the property of their respective owners in the United States or other countries. The absence of a trademark symbol does not constitute a waiver of Lattice Semiconductor's trademarks or other intellectual property rights with regard to a product name, logo or slogan.

## Export Controlled Document

This document contains materials that are subject to the U.S. Export Administration Regulations and may also be subject to additional export control laws and regulations (collectively "Export Laws") and may be used only in compliance with such Export Laws. Unless otherwise authorized by an officer of Lattice Semiconductor Corporation in writing, this document and the information contained herein (a) may not be used in relation to nuclear, biological or chemical weapons, or missiles capable of delivering these weapons, and (b) may not be re-exported or otherwise transferred to a third party who is known or suspected to be involved in relation to nuclear, biological or chemical weapons, or missiles capable of delivering these weapons, or to any sanctioned persons or entities.

## Further Information

To request other materials, documentation, and information, contact your local Lattice Semiconductor sales office or visit the Lattice Semiconductor web site at [www.latticesemi.com](http://www.latticesemi.com).

## Disclaimers

These materials are provided on an "AS IS" basis. Lattice Semiconductor Corporation and its affiliates disclaim all representations and warranties (express, implied, statutory or otherwise), including but not limited to: (i) all implied warranties of merchantability, fitness for a particular purpose, and/or non-infringement of third party rights; (ii) all warranties arising out of course-of-dealing, usage, and/or trade; and (iii) all warranties that the information or results provided in, or that may be obtained from use of, the materials are accurate, reliable, complete, up-to-date, or produce specific outcomes. Lattice Semiconductor Corporation and its affiliates assume no liability or responsibility for any errors or omissions in these materials, makes no commitment or warranty to correct any such errors or omissions or update or keep current the information contained in these materials, and expressly disclaims all direct, indirect, special, incidental, consequential, reliance and punitive damages, including WITHOUT LIMITATION any loss of profits arising out of your access to, use or interpretation of, or actions taken or not taken based on the content of these materials. Lattice Semiconductor Corporation and its affiliates reserve the right, without notice, to periodically modify the information in these materials, and to add to, delete, and/or change any of this information.

## Products and Services

The products and services described in these materials, and any other information, services, designs, know-how and/or products provided by Lattice Semiconductor Corporation and/or its affiliates are provided on "AS IS" basis, except to the extent that Lattice Semiconductor Corporation and/or its affiliates provides an applicable written limited warranty in its standard form license agreements, standard Terms and Conditions of Sale and Service or its other applicable standard form agreements, in which case such limited warranty shall apply and shall govern in lieu of all other warranties (express, statutory, or implied). EXCEPT FOR SUCH LIMITED WARRANTY, LATTICE SEMICONDUCTOR CORPORATION AND ITS AFFILIATES DISCLAIM ALL REPRESENTATIONS AND WARRANTIES (EXPRESS, IMPLIED, STATUTORY OR OTHERWISE), REGARDING THE INFORMATION, SERVICES, DESIGNS, KNOW-HOW AND PRODUCTS PROVIDED BY LATTICE SEMICONDUCTOR CORPORATION AND/OR ITS AFFILIATES, INCLUDING BUT NOT LIMITED TO, ALL IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, AND/OR NON-INFRINGEMENT OF THIRD PARTY RIGHTS. YOU ACKNOWLEDGE AND AGREE THAT SUCH INFORMATION, SERVICES, DESIGNS, KNOW-HOW AND PRODUCTS HAVE NOT BEEN DESIGNED, TESTED, OR MANUFACTURED FOR USE OR RESALE IN SYSTEMS WHERE THE FAILURE, MALFUNCTION, OR ANY INACCURACY OF THESE ITEMS CARRIES A RISK OF DEATH OR SERIOUS BODILY INJURY, INCLUDING, BUT NOT LIMITED TO, USE IN NUCLEAR FACILITIES, AIRCRAFT NAVIGATION OR COMMUNICATION, EMERGENCY SYSTEMS, OR OTHER SYSTEMS WITH A SIMILAR DEGREE OF POTENTIAL HAZARD. NO PERSON IS AUTHORIZED TO MAKE ANY OTHER WARRANTY OR REPRESENTATION CONCERNING THE PERFORMANCE OF THE INFORMATION, PRODUCTS, KNOW-HOW, DESIGNS OR SERVICES OTHER THAN AS PROVIDED IN THESE TERMS AND CONDITIONS.

- Four DLLs and four PLLs in LFE5-45 and LFE5-85; two DLLs and two PLLs in LFE5-25 and LFE5-12
- Pre-Engineered Source Synchronous I/O
  - DDR registers in I/O cells
  - Dedicated read/write levelling functionality
  - Dedicated gearing logic
  - Source synchronous standards support
    - ADC/DAC, 7:1 LVDS, XGMII
    - High Speed ADC/DAC devices
  - Dedicated DDR2/DDR3 and LPDDR2/LPDDR3 memory support with DQS logic, up to 800 Mb/s data-rate
- Programmable sysI/O™ Buffer Supports Wide Range of Interfaces
  - On-chip termination
  - LVTTTL and LVCMOS 33/25/18/15/12
  - SSTL 18/15 I, II
  - HSUL12
  - LVDS, Bus-LVDS, LVPECL, RSDS, MLVDS
  - subLVDS and SLVS, MIPI D-PHY input interfaces
- Flexible Device Configuration
  - Shared bank for configuration I/Os
  - SPI boot flash interface
  - Dual-boot images supported
  - Slave SPI
  - TransFR™ I/O for simple field updates
- Single Event Upset (SEU) Mitigation Support
  - Soft Error Detect – Embedded hard macro
  - Soft Error Correction – Without stopping user operation
  - Soft Error Injection – Emulate SEU event to debug system error handling
- System Level Support
  - IEEE 1149.1 and IEEE 1532 compliant
  - Reveal Logic Analyzer
  - On-chip oscillator for initialization and general use
  - 1.1 V core power supply for ECP5, 1.2 V core power supply for ECP5UM5G

**Table 1.1. ECP5 and ECP5-5G Family Selection Guide**

Device	LFE5UM-25 LFE5UM5G-25	LFE5UM-45 LFE5UM5G-45	LFE5UM-85 LFE5UM5G-85	LFE5U- 12	LFE5U- 25	LFE5U- 45	LFE5U- 85
LUTs (K)	24	44	84	12	24	44	84
sysMEM Blocks (18 Kb)	56	108	208	32	56	108	208
Embedded Memory (Kb)	1,008	1944	3744	576	1,008	1944	3744
Distributed RAM Bits (Kb)	194	351	669	97	194	351	669
18 X 18 Multipliers	28	72	156	28	28	72	156
SERDES (Dual/Channels)	1/2	2/4	2/4	0	0	0	0
PLLs/DLLs	2/2	4/4	4/4	2/2	2/2	4/4	4/4
<b>Packages (SERDES Channels / IO Count)</b>							
256 caBGA (14 x 14 mm <sup>2</sup> , 0.8 mm)	—	—	—	0/197	0/197	0/197	—
285 csfBGA (10 x 10 mm <sup>2</sup> , 0.5 mm)	2/118	2/118	2/118	0/118	0/118	0/118	0/118
381 caBGA (17 x 17 mm <sup>2</sup> , 0.8 mm)	2/197	4/203	4/205	0/197	0/197	0/203	0/205
554 caBGA (23 x 23 mm <sup>2</sup> , 0.8 mm)	—	4/245	4/259	—	—	0/245	0/259
756 caBGA (27 x 27 mm <sup>2</sup> , 0.8 mm)	—	—	4/365	—	—	—	0/365

## 2.2.2. Modes of Operation

Slices 0-2 have up to four potential modes of operation: Logic, Ripple, RAM and ROM. Slice 3 is not needed for RAM mode, it can be used in Logic, Ripple, or ROM modes.

### Logic Mode

In this mode, the LUTs in each slice are configured as 4-input combinatorial lookup tables. A LUT4 can have 16 possible input combinations. Any four input logic functions can be generated by programming this lookup table. Since there are two LUT4s per slice, a LUT5 can be constructed within one slice. Larger look-up tables such as LUT6, LUT7 and LUT8 can be constructed by concatenating other slices. Note that LUT8 requires more than four slices.

### Ripple Mode

Ripple mode supports the efficient implementation of small arithmetic functions. In ripple mode, the following functions can be implemented by each slice:

- Addition 2-bit
- Subtraction 2-bit
- Add/Subtract 2-bit using dynamic control
- Up counter 2-bit
- Down counter 2-bit
- Up/Down counter with asynchronous clear
- Up/Down counter with preload (sync)
- Ripple mode multiplier building block
- Multiplier support
- Comparator functions of A and B inputs
  - A greater-than-or-equal-to B
  - A not-equal-to B
  - A less-than-or-equal-to B

Ripple Mode includes an optional configuration that performs arithmetic using fast carry chain methods. In this configuration (also referred to as CCU2 mode) two additional signals, Carry Generate and Carry Propagate, are generated on a per slice basis to allow fast arithmetic functions to be constructed by concatenating Slices.

### RAM Mode

In this mode, a 16x4-bit distributed single port RAM (SPR) can be constructed in one PFU using each LUT block in Slice 0 and Slice 1 as a 16 x 2-bit memory in each slice. Slice 2 is used to provide memory address and control signals.

A 16 x 2-bit pseudo dual port RAM (PDPR) memory is created in one PFU by using one Slice as the read-write port and the other companion slice as the read-only port. The slice with the read-write port updates the SRAM data contents in both slices at the same write cycle.

ECP5/ECP5-5G devices support distributed memory initialization.

The Lattice design tools support the creation of a variety of different size memories. Where appropriate, the software will construct these using distributed memory primitives that represent the capabilities of the PFU. [Table 2.3](#) lists the number of slices required to implement different distributed RAM primitives. For more information about using RAM in ECP5/ECP5-5G devices, refer to [ECP5 and ECP5-5G Memory Usage Guide \(TN1264\)](#).

**Table 2.3. Number of Slices Required to Implement Distributed RAM**

	SPR 16 X 4	PDPR 16 X 4
Number of slices	3	6

**Note:** SPR = Single Port RAM, PDPR = Pseudo Dual Port RAM

### ROM Mode

ROM mode uses the LUT logic; hence, Slices 0 through 3 can be used in ROM mode. Preloading is accomplished through the programming interface during PFU configuration.

For more information, refer to [ECP5 and ECP5-5G Memory Usage Guide \(TN1264\)](#).

Table 2.4 provides a description of the signals in the PLL blocks.

**Table 2.4. PLL Blocks Signal Descriptions**

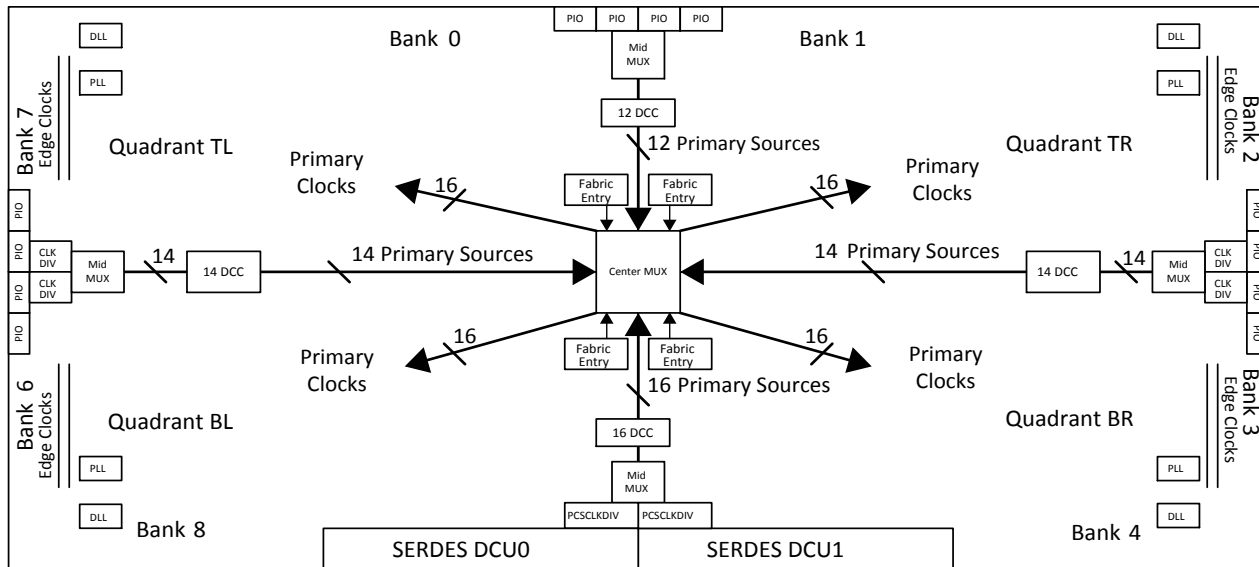
Signal	Type	Description
CLKI	Input	Clock Input to PLL from external pin or routing
CLKI2	Input	Muxed clock input to PLL
SEL	Input	Input Clock select, selecting from CLKI and CLKI2 inputs
CLKFB	Input	PLL Feedback Clock
PHASESEL[1:0]	Input	Select which output to be adjusted on Phase by PHASEDIR, PHASESTEP, PHASELOADREG
PHASEDIR	Input	Dynamic Phase adjustment direction.
PHASESTEP	Input	Dynamic Phase adjustment step.
PHASELOADREG	Input	Load dynamic phase adjustment values into PLL.
CLKOP	Output	Primary PLL output clock (with phase shift adjustment)
CLKOS	Output	Secondary PLL output clock (with phase shift adjust)
CLKOS2	Output	Secondary PLL output clock2 (with phase shift adjust)
CLKOS3	Output	Secondary PLL output clock3 (with phase shift adjust)
LOCK	Output	PLL LOCK to CLKI, Asynchronous signal. Active high indicates PLL lock
STDBY	Input	Standby signal to power down the PLL
RST	Input	Resets the PLL
ENCLKOP	Input	Enable PLL output CLKOP
ENCLKOS	Input	Enable PLL output CLKOS
ENCLKOS2	Input	Enable PLL output CLKOS2
ENCLKOS3	Input	Enable PLL output CLKOS3

For more details on the PLL you can refer to the [ECP5 and ECP5-5G sysClock PLL/DLL Design and Usage Guide \(TN1263\)](#).

## 2.5. Clock Distribution Network

There are two main clock distribution networks for any member of the ECP5/ECP5-5G product family, namely Primary Clock (PCLK) and Edge Clock (ECLK). These clock networks have the clock sources come from many different sources, such as Clock Pins, PLL outputs, DLLDEL outputs, Clock divider outputs, SERDES/PCS clocks and some on chip generated clock signal. There are clock dividers (CLKDIV) blocks to provide the slower clock from these clock sources. ECP5/ECP5-5G also supports glitchless dynamic enable function (DCC) for the PCLK Clock to save dynamic power. There are also some logics to allow dynamic glitchless selection between two clocks for the PCLK network (DCS).

Overview of Clocking Network is shown in [Figure 2.6](#) on page 20 for LFE5UM/LFE5UM5G-85 device.



**Figure 2.6. LFE5UM/LFE5UM5G-85 Clocking**

### 2.5.1. Primary Clocks

The ECP5/ECP5-5G device family provides low-skew, high fan-out clock distribution to all synchronous elements in the FPGA fabric through the Primary Clock Network.

The primary clock network is divided into four clocking quadrants: Top Left (TL), Bottom Left (BL), Top Right (TR), and Bottom Right (BR). Each of these quadrants has 16 clocks that can be distributed to the fabric in the quadrant.

The Lattice Diamond software can automatically route each clock to one of the four quadrants up to a maximum of 16 clocks per quadrant. The user can change how the clocks are routed by specifying a preference in the Lattice Diamond software to locate the clock to specific. The ECP5/ECP5-5G device provides the user with a maximum of 64 unique clock input sources that can be routed to the primary Clock network.

Primary clock sources are:

- Dedicated clock input pins
- PLL outputs
- CLKDIV outputs
- Internal FPGA fabric entries (with minimum general routing)
- SERDES/PCS/PCSDIV clocks
- OSC clock

These sources are routed to one of four clock switches called a Mid Mux. The outputs of the Mid MUX are routed to the center of the FPGA where another clock switch, called the Center MUX, is used to route the primary clock sources to primary clock distribution to the ECP5/ECP5-5G fabric. These routing muxes are shown in Figure 2.6. Since there is a maximum of 60 unique clock input sources to the clocking quadrants, there are potentially 64 unique clock domains that can be used in the ECP5/ECP5-5G Device. For more information about the primary clock tree and connections, refer to [ECP5 and ECP5-5G sysClock PLL/DLL Design and Usage Guide \(TN1263\)](#).

#### 2.5.1.1. Dynamic Clock Control

The Dynamic Clock Control (DCC), Quadrant Clock enable/disable feature allows internal logic control of the quadrant primary clock network. When a clock network is disabled, the clock signal is static and not toggle. All the logic fed by that clock will not toggle, reducing the overall power consumption of the device. The disable function will not create glitch and increase the clock latency to the primary clock network.

This DCC controls the clock sources from the Primary CLOCK MIDMUX before they are fed to the Primary Center MUXs that drive the quadrant clock network. For more information about the DCC, refer to [ECP5 and ECP5-5G sysClock PLL/DLL Design and Usage Guide \(TN1263\)](#).

### 2.11.1.1. Input FIFO

The ECP5/ECP5-5G PIO has dedicated input FIFO per single-ended pin for input data register for DDR Memory interfaces. The FIFO resides before the gearing logic. It transfers data from DQS domain to continuous ECLK domain. On the Write side of the FIFO, it is clocked by DQS clock which is the delayed version of the DQS Strobe signal from DDR memory. On the Read side of FIFO, it is clocked by ECLK. ECLK may be any high speed clock with identical frequency as DQS (the frequency of the memory chip). Each DQS group has one FIFO control block. It distributes FIFO read/write pointer to every PIC in same DQS group. DQS Grouping and DQS Control Block is described in [DDR Memory Support](#) section on page 35.

**Table 2.8. Input Block Port Description**

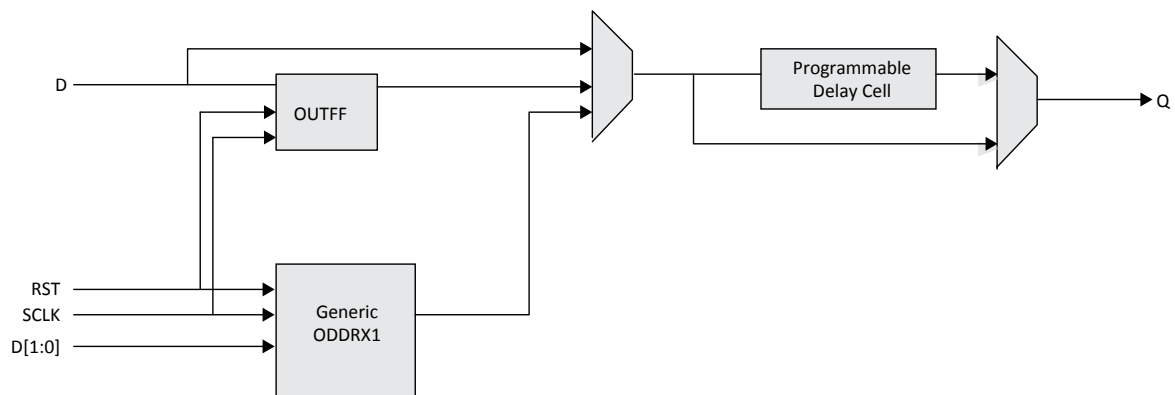
Name	Type	Description
D	Input	High Speed Data Input
Q[1:0]/Q[3:0]/Q[6:0]	Output	Low Speed Data to the device core
RST	Input	Reset to the Output Block
SCLK	Input	Slow Speed System Clock
ECLK	Input	High Speed Edge Clock
DQS	Input	Clock from DQS control Block used to clock DDR memory data
ALIGNWD	Input	Data Alignment signal from device core.

### 2.11.2. Output Register Block

The output register block registers signal from the core of the device before they are passed to the sysIO buffers.

ECP5/ECP5-5G output data path has output programmable flip flops and output gearing logic. On the left and right sides, the output register block can support 1x, 2x and 7:1 gearing enabling high speed DDR interfaces and DDR memory interfaces. On the top side, the banks support 1x gearing. ECP5/ECP5-5G output data path diagram is shown in [Figure 2.19](#). The programmable delay cells are also available in the output data path.

For detailed description of the output register block modes and usage, refer to [ECP5 and ECP5-5G High-Speed I/O Interface \(TN1265\)](#).



**Figure 2.19. Output Register Block on Top Side**

#### 2.14.4. On-Chip Programmable Termination

The ECP5/ECP5-5G devices support a variety of programmable on-chip terminations options, including:

- Dynamically switchable Single-Ended Termination with programmable resistor values of 50  $\Omega$ , 75  $\Omega$ , or 150  $\Omega$ .
- Common mode termination of 100  $\Omega$  for differential inputs.

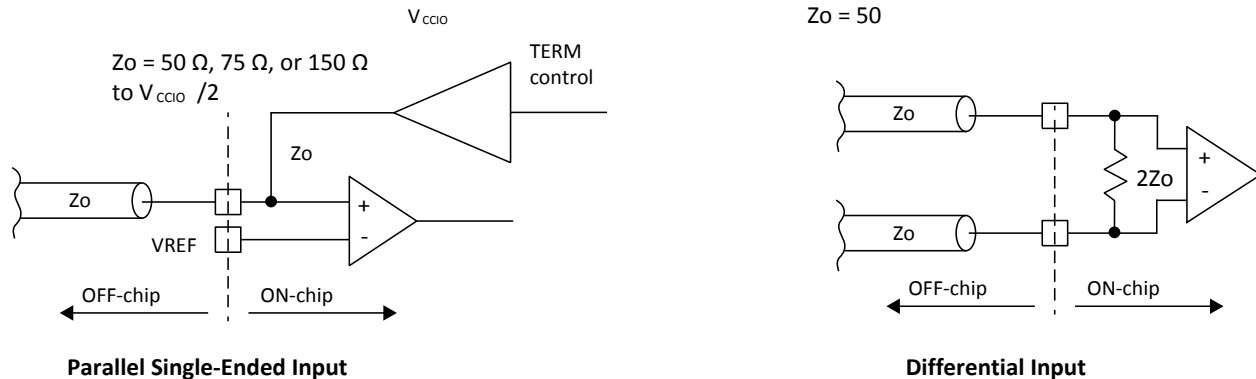


Figure 2.26. On-Chip Termination

See Table 2.12 for termination options for input modes.

Table 2.12. On-Chip Termination Options for Input Modes

IO_TYPE	Terminate to $V_{CCIO}/2^*$	Differential Termination Resistor*
LVDS25	—	100
BLVDS25	—	100
MLVDS	—	100
LVPECL33	—	100
subLVDS	—	100
SLVS	—	100
HSUL12	50, 75, 150	—
HSUL12D	—	100
SSTL135_I / II	50, 75, 150	—
SSTL135D_I / II	—	100
SSTL15_I / II	50, 75, 150	—
SSTL15D_I / II	—	100
SSTL18_I / II	50, 75, 150	—
SSTL18D_I / II	—	100

**\*Notes:**

TERMINATE to  $V_{CCIO}/2$  (Single-Ended) and DIFFERENTIAL TERMINATION RESISTOR when turned on can only have one setting per bank. Only left and right banks have this feature.

Use of TERMINATE to  $V_{CCIO}/2$  and DIFFERENTIAL TERMINATION RESISTOR are mutually exclusive in an I/O bank. On-chip termination tolerance  $\pm 20\%$ .

Refer to [ECP5 and ECP5-5G sysIO Usage Guide \(TN1262\)](#) for on-chip termination usage and value ranges.

#### 2.14.5. Hot Socketing

ECP5/ECP5-5G devices have been carefully designed to ensure predictable behavior during power-up and power-down. During power-up and power-down sequences, the I/Os remain in tristate until the power supply voltage is high enough to ensure reliable operation. In addition, leakage into I/O pins is controlled within specified limits. See the [Hot Socketing Specifications](#) section on page 48.



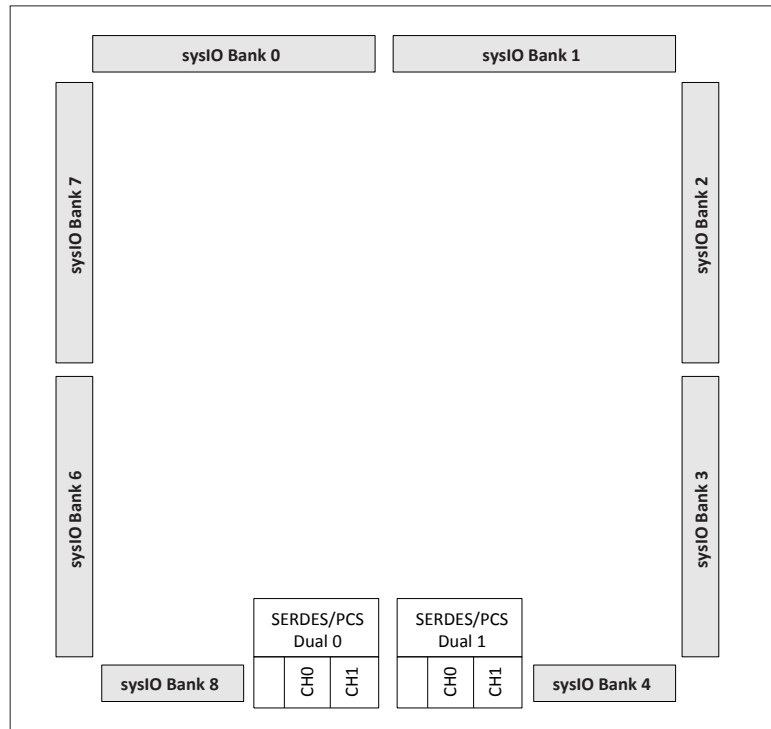


Figure 2.27. SERDES/PCS Duals (LFE5UM/LFE5UM5G-85)

Table 2.13. LFE5UM/LFE5UM5G SERDES Standard Support

Standard	Data Rate (Mb/s)	Number of General/Link Width	Encoding Style
PCI Express 1.1 and 2.0 2.02	2500	x1, x2, x4	8b10b
	5000 <sup>2</sup>	x1, x2	8b10b
Gigabit Ethernet	1250	x1	8b10b
SGMII	1250	x1	8b10b
	2500	x1	8b10b
XAUI	3125	x4	8b10b
CPRI-1 CPRI-2 CPRI-3 CPRI-4 CPRI-5	614.4 1228.8 2457.6 3072.0 4915.2 <sup>2</sup>	x1	8b10b
SD-SDI (259M, 344M) <sup>1</sup>	270	x1	NRZI/Scrambled
HD-SDI (292M)	1483.5	x1	NRZI/Scrambled
	1485	x1	NRZI/Scrambled
3G-SDI (424M)	2967 2970	x1	NRZI/Scrambled
	5000	—	—
JESD204A/B	3125	x1	8b/10b

**Notes:**

1. For SD-SDI rate, the SERDES is bypassed and SERDES input signals are directly connected to the FPGA routing.
2. For ECP5-5G family devices only.

## 2.18. Device Configuration

All ECP5/ECP5-5G devices contain two ports that can be used for device configuration. The Test Access Port (TAP), which supports bit-wide configuration, and the sysCONFIG port, support dual-byte, byte and serial configuration. The TAP supports both the IEEE Standard 1149.1 Boundary Scan specification and the IEEE Standard 1532 In-System Configuration specification. There are 11 dedicated pins for TAP and sysConfig supports (TDI, TDO, TCK, TMS, CFG[2:0], PROGRAMN, DONE, INITN and CCLK). The remaining sysCONFIG pins are used as dual function pins. Refer to [ECP5 and ECP5-5G sysCONFIG Usage Guide \(TN1260\)](#) for more information about using the dual-use pins as general purpose I/Os.

There are various ways to configure an ECP5/ECP5-5G device:

- JTAG
- Standard Serial Peripheral Interface (SPI) – Interface to boot PROM Support x1, x2, x4 wide SPI memory interfaces.
- System microprocessor to drive a x8 CPU port SPCM mode
- System microprocessor to drive a serial slave SPI port (SSPI mode)
- Slave Serial model (SCM)

On power-up, the FPGA SRAM is ready to be configured using the selected sysCONFIG port. Once a configuration port is selected, it will remain active throughout that configuration cycle. The IEEE 1149.1 port can be activated any time after power-up by sending the appropriate command through the TAP port.

ECP5/ECP5-5G devices also support the Slave SPI Interface. In this mode, the FPGA behaves like a SPI Flash device (slave mode) with the SPI port of the FPGA to perform read-write operations.

### 2.18.1. Enhanced Configuration Options

ECP5/ECP5-5G devices have enhanced configuration features such as: decryption support, decompression support, TransFR™ I/O and dual-boot and multi-boot image support.

#### TransFR (Transparent Field Reconfiguration)

TransFR I/O (TFR) is a unique Lattice technology that allows users to update their logic in the field without interrupting system operation using a single ispVM command. TransFR I/O allows I/O states to be frozen during device configuration. This allows the device to be field updated with a minimum of system disruption and downtime. Refer to [Minimizing System Interruption During Configuration Using TransFR Technology \(TN1087\)](#) for details.

#### Dual-Boot and Multi-Boot Image Support

Dual-boot and multi-boot images are supported for applications requiring reliable remote updates of configuration data for the system FPGA. After the system is running with a basic configuration, a new boot image can be downloaded remotely and stored in a separate location in the configuration storage device. Any time after the update the ECP5/ECP5-5G devices can be re-booted from this new configuration file. If there is a problem, such as corrupt data during download or incorrect version number with this new boot image, the ECP5/ECP5-5G device can revert back to the original backup golden configuration and try again. This all can be done without power cycling the system. For more information, refer to [ECP5 and ECP5-5G sysCONFIG Usage Guide \(TN1260\)](#).

### 2.18.2. Single Event Upset (SEU) Support

ECP5/ECP5-5G devices support SEU mitigation with three supporting functions:

- SED – Soft Error Detect
- SEC – Soft Error Correction
- SEI – Soft Error Injection

ECP5/ECP5-5G devices have dedicated logic to perform Cycle Redundancy Code (CRC) checks. During configuration, the configuration data bitstream can be checked with the CRC logic block. In addition, the ECP5/ECP5-5G device can also be programmed to utilize a Soft Error Detect (SED) mode that checks for soft errors in configuration SRAM. The SED operation can be run in the background during user mode. If a soft error occurs, during user mode (normal operation) the device can be programmed to generate an error signal.

### 3.7. Hot Socketing Requirements

**Table 3.6. Hot Socketing Requirements**

Description	Min	Typ	Max	Unit
Input current per SERDES I/O pin when device is powered down and inputs driven.	—	—	8	mA
Input current per HDIN pin when device power supply is off, inputs driven <sup>1, 2</sup>	—	—	15	mA
Current per HDIN pin when device power ramps up, input driven <sup>3</sup>	—	—	50	mA
Current per HDOUT pin when device power supply is off, outputs pulled up <sup>4</sup>	—	—	30	mA

**Notes:**

1. Device is powered down with all supplies grounded, both HDINP and HDINN inputs driven by a CML driver with maximum allowed output  $V_{CCHTX}$ , 8b/10b data, no external AC coupling.
2. Each P and N input must have less than the specified maximum input current during hot plug. For a device with 2 DCU, the total input current would be 15 mA \* 4 channels \* 2 input pins per channel = 120 mA.
3. Device power supplies are ramping up ( $V_{CCA}$  and  $V_{CCAUX}$ ), both HDINP and HDINN inputs are driven by a CML driver with maximum allowed output  $V_{CCHTX}$ , 8b/10b data, internal AC coupling.
4. Device is powered down with all supplies grounded. Both HDOUTP and HDOUN outputs are pulled up to  $V_{CCHTX}$  by the far end receiver termination of 50  $\Omega$  single ended.

### 3.8. ESD Performance

Refer to the [ECP5 and ECP5-5G Product Family Qualification Summary](#) for complete qualification data, including ESD performance.

### 3.9. DC Electrical Characteristics

Over Recommended Operating Conditions

**Table 3.7. DC Electrical Characteristics**

Symbol	Parameter	Condition	Min	Typ	Max	Unit
$I_{IL}, I_{IH}^{1, 4}$	Input or I/O Low Leakage	$0 \leq V_{IN} \leq V_{CCIO}$	—	—	10	$\mu A$
$I_{IH}^{1, 3}$	Input or I/O High Leakage	$V_{CCIO} < V_{IN} \leq V_{IH(MAX)}$	—	—	100	$\mu A$
$I_{PU}$	I/O Active Pull-up Current, sustaining logic HIGH state	$0.7 V_{CCIO} \leq V_{IN} \leq V_{CCIO}$	–30	—	—	$\mu A$
	I/O Active Pull-up Current, pulling down from logic HIGH state	$0 \leq V_{IN} \leq 0.7 V_{CCIO}$	—	—	–150	$\mu A$
$I_{PD}$	I/O Active Pull-down Current, sustaining logic LOW state	$0 \leq V_{IN} \leq V_{IL(MAX)}$	30	—	—	$\mu A$
	I/O Active Pull-down Current, pulling up from logic LOW state	$0 \leq V_{IN} \leq V_{CCIO}$	—	—	150	$\mu A$
C1	I/O Capacitance <sup>2</sup>	$V_{CCIO} = 3.3 V, 2.5 V, 1.8 V, 1.5 V, 1.2 V, V_{CC} = 1.2 V, V_{IO} = 0 \text{ to } V_{IH(MAX)}$	—	5	8	pf
C2	Dedicated Input Capacitance <sup>2</sup>	$V_{CCIO} = 3.3 V, 2.5 V, 1.8 V, 1.5 V, 1.2 V, V_{CC} = 1.2 V, V_{IO} = 0 \text{ to } V_{IH(MAX)}$	—	5	7	pf
$V_{HYST}$	Hysteresis for Single-Ended Inputs	$V_{CCIO} = 3.3 V$	—	300	—	mV
		$V_{CCIO} = 2.5 V$	—	250	—	mV

**Notes:**

1. Input or I/O leakage current is measured with the pin configured as an input or as an I/O with the output driver tristated. It is not measured with the output driver active. Bus maintenance circuits are disabled.
2.  $T_A$  25 °C,  $f = 1.0$  MHz.
3. Applicable to general purpose I/Os in top and bottom banks.
4. When used as  $V_{REF}$ , maximum leakage = 25  $\mu A$ .

### 3.14.4. LVDS25E

The top and bottom sides of ECP5/ECP5-5G devices support LVDS outputs via emulated complementary LVCMOS outputs in conjunction with a parallel resistor across the driver outputs. The scheme shown in Figure 3.1 is one possible solution for point-to-point signals.

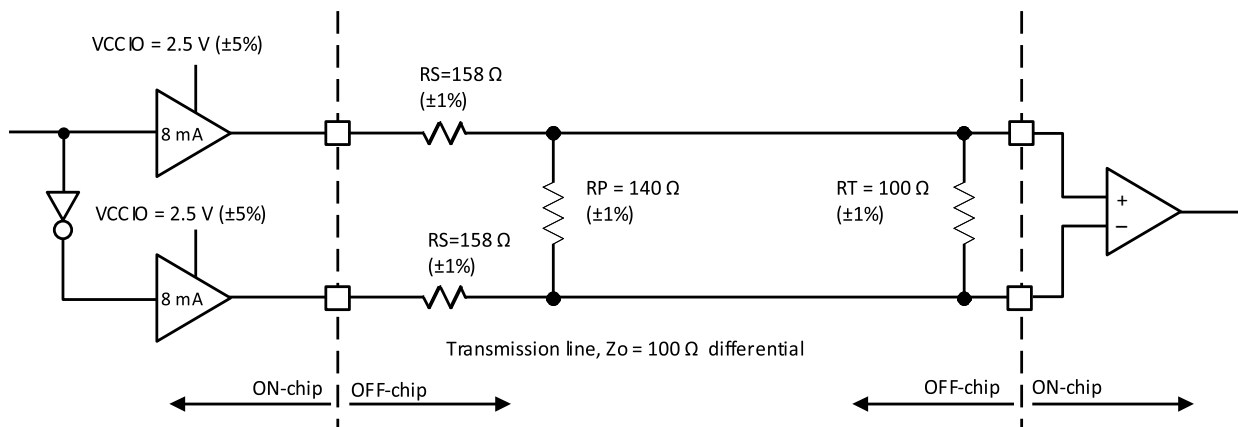


Figure 3.1. LVDS25E Output Termination Example

Table 3.14. LVDS25E DC Conditions

Parameter	Description	Typical	Unit
V <sub>CCIO</sub>	Output Driver Supply (±5%)	2.50	V
Z <sub>OUT</sub>	Driver Impedance	20	Ω
R <sub>S</sub>	Driver Series Resistor (±1%)	158	Ω
R <sub>P</sub>	Driver Parallel Resistor (±1%)	140	Ω
R <sub>T</sub>	Receiver Termination (±1%)	100	Ω
V <sub>OH</sub>	Output High Voltage	1.43	V
V <sub>OL</sub>	Output Low Voltage	1.07	V
V <sub>OD</sub>	Output Differential Voltage	0.35	V
V <sub>CM</sub>	Output Common Mode Voltage	1.25	V
Z <sub>BACK</sub>	Back Impedance	100.5	Ω
I <sub>DC</sub>	DC Output Current	6.03	mA

**Note:** For input buffer, see LVDS Table 3.13 on page 55.

### 3.18. External Switching Characteristics

Over recommended commercial operating conditions.

**Table 3.22. ECP5/ECP5-5G External Switching Characteristics**

Parameter	Description	Device	-8		-7		-6		Unit
			Min	Max	Min	Max	Min	Max	
Clocks									
Primary Clock									
f <sub>MAX_PRI</sub>	Frequency for Primary Clock Tree	—	—	370	—	303	—	257	MHz
t <sub>W_PRI</sub>	Clock Pulse Width for Primary Clock	—	0.8	—	0.9	—	1.0	—	ns
t <sub>SKEW_PRI</sub>	Primary Clock Skew within a Device	—	—	420	—	462	—	505	ps
Edge Clock									
f <sub>MAX_EDGE</sub>	Frequency for Edge Clock Tree	—	—	400	—	350	—	312	MHz
t <sub>W_EDGE</sub>	Clock Pulse Width for Edge Clock	—	1.175	—	1.344	—	1.50	—	ns
t <sub>SKEW_EDGE</sub>	Edge Clock Skew within a Bank	—	—	160	—	180	—	200	ps
Generic SDR Input									
General I/O Pin Parameters Using Dedicated Primary Clock Input without PLL									
t <sub>CO</sub>	Clock to Output - PIO Output Register	All Devices	—	5.4	—	6.1	—	6.8	ns
t <sub>SU</sub>	Clock to Data Setup - PIO Input Register	All Devices	0	—	0	—	0	—	ns
t <sub>H</sub>	Clock to Data Hold - PIO Input Register	All Devices	2.7	—	3	—	3.3	—	ns
t <sub>SU_DEL</sub>	Clock to Data Setup - PIO Input Register with Data Input Delay	All Devices	1.2	—	1.33	—	1.46	—	ns
t <sub>H_DEL</sub>	Clock to Data Hold - PIO Input Register with Data Input Delay	All Devices	0	—	0	—	0	—	ns
f <sub>MAX_IO</sub>	Clock Frequency of I/O and PFU Register	All Devices	—	400	—	350	—	312	MHz
General I/O Pin Parameters Using Dedicated Primary Clock Input with PLL									
t <sub>COPLL</sub>	Clock to Output - PIO Output Register	All Devices	—	3.5	—	3.8	—	4.1	ns
t <sub>SUPLL</sub>	Clock to Data Setup - PIO Input Register	All Devices	0.7	—	0.78	—	0.85	—	ns
t <sub>HPLL</sub>	Clock to Data Hold - PIO Input Register	All Devices	0.8	—	0.89	—	0.98	—	ns
t <sub>SU_DEPLL</sub>	Clock to Data Setup - PIO Input Register with Data Input Delay	All Devices	1.6	—	1.78	—	1.95	—	ns

### 3.20. SERDES High-Speed Data Transmitter

**Table 3.24. Serial Output Timing and Levels**

Symbol	Description	Min	Typ	Max	Unit
V <sub>TX-DIFF-PP</sub>	Peak-Peak Differential voltage on selected amplitude <sup>1, 2</sup>	-25%	—	25%	mV, p-p
V <sub>TX-CM-DC</sub>	Output common mode voltage	—	V <sub>CCHTX</sub> / 2	—	mV, p-p
T <sub>TX-R</sub>	Rise time (20% to 80%)	50	—	—	ps
T <sub>TX-F</sub>	Fall time (80% to 20%)	50	—	—	ps
T <sub>TX-CM-AC-P</sub>	RMS AC peak common-mode output voltage	—	—	20	mV
Z <sub>TX-SE</sub>	Single ended output impedance for 50/75 Ω	-20%	50/75	20%	Ω
	Single ended output impedance for 6K Ω	-25%	6K	25%	Ω
RL <sub>TX-DIFF</sub>	Differential return loss (with package included) <sup>3</sup>	—	—	-10	dB
RL <sub>TX-COM</sub>	Common mode return loss (with package included) <sup>3</sup>	—	—	-6	dB

**Notes:**

1. Measured with 50 Ω Tx Driver impedance at V<sub>CCHTX</sub>±5%.
2. Refer to [ECP5 and ECP5-5G SERDES/PCS Usage Guide \(TN1261\)](#) for settings of Tx amplitude.
3. Return los = -10 dB (differential), -6 dB (common mode) for 100 MHz ≤ f ≤ 1.6 GHz with 50 Ω output impedance configuration. This includes degradation due to package effects.

**Table 3.25. Channel Output Jitter**

Description	Frequency	Min	Typ	Max	Unit
Deterministic	5 Gb/s	—	—	TBD	UI, p-p
Random	5 Gb/s	—	—	TBD	UI, p-p
Total	5 Gb/s	—	—	TBD	UI, p-p
Deterministic	3.125 Gb/s	—	—	0.17	UI, p-p
Random	3.125 Gb/s	—	—	0.25	UI, p-p
Total	3.125 Gb/s	—	—	0.35	UI, p-p
Deterministic	2.5 Gb/s	—	—	0.17	UI, p-p
Random	2.5 Gb/s	—	—	0.20	UI, p-p
Total	2.5 Gb/s	—	—	0.35	UI, p-p
Deterministic	1.25 Gb/s	—	—	0.10	UI, p-p
Random	1.25 Gb/s	—	—	0.22	UI, p-p
Total	1.25 Gb/s	—	—	0.24	UI, p-p

**Notes:**

1. Values are measured with PRBS 2<sup>7</sup>-1, all channels operating, FPGA logic active, I/Os around SERDES pins quiet, reference clock @ 10X mode.
2. For ECP5-5G family devices only.

## 3.22. SERDES High-Speed Data Receiver

**Table 3.27. Serial Input Data Specifications**

Symbol	Description	Min	Typ	Max	Unit
$V_{RX-DIFF-S}$	Differential input sensitivity	150	—	1760	mV, p-p
$V_{RX-IN}$	Input levels	0	—	$V_{CCA} + 0.5^2$	V
$V_{RX-CM-DCCM}$	Input common mode range (internal DC coupled mode)	0.6	—	$V_{CCA}$	V
$V_{RX-CM-ACCM}$	Input common mode range (internal AC coupled mode) <sup>2</sup>	0.1	—	$V_{CCA} + 0.2$	V
$T_{RX-RELOCK}$	SCDR re-lock time <sup>1</sup>	—	1000	—	Bits
$Z_{RX-TERM}$	Input termination 50/75 $\Omega$ /High Z	–20%	50/75/5 K	+20%	$\Omega$
$RL_{RX-RL}$	Return loss (without package)	—	—	–10	dB

**Notes:**

1. This is the typical number of bit times to re-lock to a new phase or frequency within  $\pm 300$  ppm, assuming 8b10b encoded data.
2. Up to 1.655 for ECP5, and 1.76 for ECP5-5G.

## 3.23. Input Data Jitter Tolerance

A receiver's ability to tolerate incoming signal jitter is very dependent on jitter type. High speed serial interface standards have recognized the dependency on jitter type and have specifications to indicate tolerance levels for different jitter types as they relate to specific protocols. Sinusoidal jitter is considered to be a worst case jitter type.

**Table 3.28. Receiver Total Jitter Tolerance Specification**

Description	Frequency	Condition	Min	Typ	Max	Unit
Deterministic	5 Gb/s	400 mV differential eye	—	—	TBD	UI, p-p
Random		400 mV differential eye	—	—	TBD	UI, p-p
Total		400 mV differential eye	—	—	TBD	UI, p-p
Deterministic	3.125 Gb/s	400 mV differential eye	—	—	0.37	UI, p-p
Random		400 mV differential eye	—	—	0.18	UI, p-p
Total		400 mV differential eye	—	—	0.65	UI, p-p
Deterministic	2.5 Gb/s	400 mV differential eye	—	—	0.37	UI, p-p
Random		400 mV differential eye	—	—	0.18	UI, p-p
Total		400 mV differential eye	—	—	0.65	UI, p-p
Deterministic	1.25 Gb/s	400 mV differential eye	—	—	0.37	UI, p-p
Random		400 mV differential eye	—	—	0.18	UI, p-p
Total		400 mV differential eye	—	—	0.65	UI, p-p

**Notes:**

1. Jitter tolerance measurements are done with protocol compliance tests: 3.125 Gb/s - XAUI Standard, 2.5 Gb/s - PCIe Standard, 1.25 Gb/s - SGMII Standard.
2. For ECP5-5G family devices only.

## 3.24. SERDES External Reference Clock

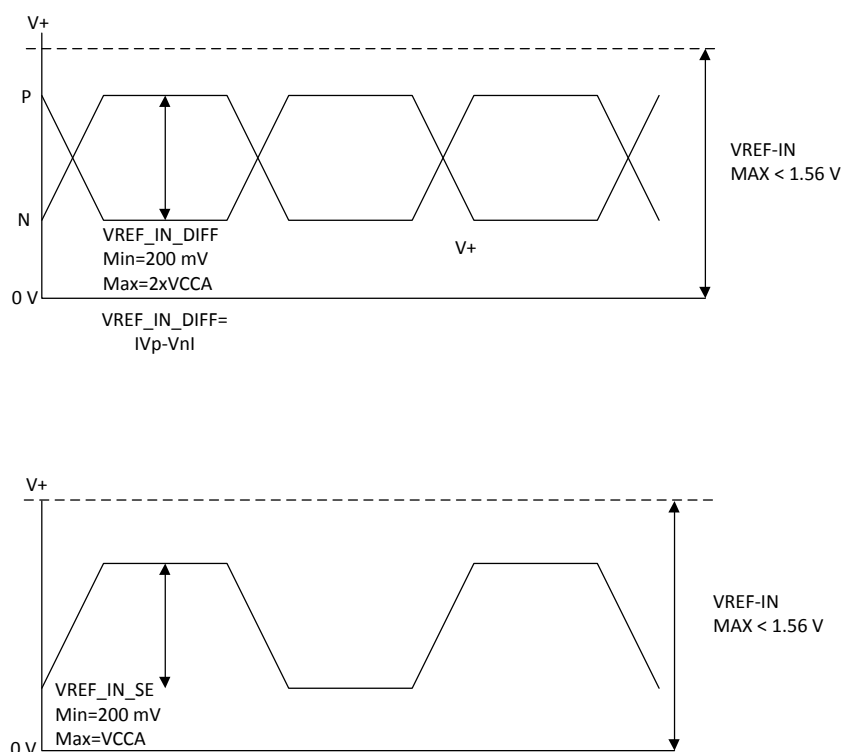
The external reference clock selection and its interface are a critical part of system applications for this product. Table 3.29 specifies reference clock requirements, over the full range of operating conditions.

**Table 3.29. External Reference Clock Specification (refclkp/refclkn)**

Symbol	Description	Min	Typ	Max	Unit
$F_{REF}$	Frequency range	50	—	320	MHz
$F_{REF-PPM}$	Frequency tolerance <sup>1</sup>	–1000	—	1000	ppm
$V_{REF-IN-SE}$	Input swing, single-ended clock <sup>2,4</sup>	200	—	$V_{CCAUXA}$	mV, p-p
$V_{REF-IN-DIFF}$	Input swing, differential clock	200	—	$2 \cdot V_{CCAUXA}$	mV, p-p differential
$V_{REF-IN}$	Input levels	0	—	$V_{CCAUXA} + 0.4$	V
$D_{REF}$	Duty cycle <sup>3</sup>	40	—	60	%
$T_{REF-R}$	Rise time (20% to 80%)	200	500	1000	ps
$T_{REF-F}$	Fall time (80% to 20%)	200	500	1000	ps
$Z_{REF-IN-TERM-DIFF}$	Differential input termination	–30%	100/HiZ	+30%	$\Omega$
$C_{REF-IN-CAP}$	Input capacitance	—	—	7	pF

**Notes:**

- Depending on the application, the PLL\_LOL\_SET and CDR\_LOL\_SET control registers may be adjusted for other tolerance values as described in [ECP5 and ECP5-5G SERDES/PCS Usage Guide \(TN1261\)](#).
- The signal swing for a single-ended input clock must be as large as the p-p differential swing of a differential input clock to get the same gain at the input receiver. With single-ended clock, a reference voltage needs to be externally connected to CLKREFN pin, and the input voltage needs to be swung around this reference voltage.
- Measured at 50% amplitude.
- Single-ended clocking is achieved by applying a reference voltage  $V_{REF}$  on REFCLKN input, with the clock applied to REFCLKP input pin.  $V_{REF}$  should be set to mid-point of the REFCLKP voltage swing.



**Figure 3.14. SERDES External Reference Clock Waveforms**



## 3.25. PCI Express Electrical and Timing Characteristics

### 3.25.1. PCIe (2.5 Gb/s) AC and DC Characteristics

Over recommended operating conditions.

**Table 3.30. PCIe (2.5 Gb/s)**

Symbol	Description	Test Conditions	Min	Typ	Max	Unit
<b>Transmit<sup>1</sup></b>						
UI	Unit interval	—	399.88	400	400.12	ps
V <sub>TX-DIFF_P-P</sub>	Differential peak-to-peak output	—	0.8	1.0	1.2	V
V <sub>TX-DE-RATIO</sub>	De-emphasis differential output voltage ratio	—	–3	–3.5	–4	dB
V <sub>TX-CM-AC_P</sub>	RMS AC peak common-mode output voltage	—	—	—	20	mV
V <sub>TX-RCV-DETECT</sub>	Amount of voltage change allowed during receiver detection	—	—	—	600	mV
V <sub>TX-CM-DC</sub>	Tx DC common mode voltage	—	0	—	V <sub>CCHTX</sub>	V
I <sub>TX-SHORT</sub>	Output short circuit current	V <sub>TX-D+</sub> =0.0 V V <sub>TX-D-</sub> =0.0 V	—	—	90	mA
Z <sub>TX-DIFF-DC</sub>	Differential output impedance	—	80	100	120	Ω
RL <sub>TX-DIFF</sub>	Differential return loss	—	10	—	—	dB
RL <sub>TX-CM</sub>	Common mode return loss	—	6.0	—	—	dB
T <sub>TX-RISE</sub>	Tx output rise time	20% to 80%	0.125	—	—	UI
T <sub>TX-FALL</sub>	Tx output fall time	20% to 80%	0.125	—	—	UI
L <sub>TX-SKEW</sub>	Lane-to-lane static output skew for all lanes in port/link	—	—	—	1.3	ns
T <sub>TX-EYE</sub>	Transmitter eye width	—	0.75	—	—	UI
T <sub>TX-EYE-MEDIAN-TO-MAX-JITTER</sub>	Maximum time between jitter median and maximum deviation from median	—	—	—	0.125	UI
<b>Receive<sup>1,2</sup></b>						
UI	Unit Interval	—	399.88	400	400.12	ps
V <sub>RX-DIFF_P-P</sub>	Differential peak-to-peak input voltage	—	0.34 <sup>3</sup>	—	1.2	V
V <sub>RX-IDLE-DET-DIFF_P-P</sub>	Idle detect threshold voltage	—	65	—	340 <sup>3</sup>	mV
V <sub>RX-CM-AC_P</sub>	RMS AC peak common-mode input voltage	—	—	—	150	mV
Z <sub>RX-DIFF-DC</sub>	DC differential input impedance	—	80	100	120	Ω
Z <sub>RX-DC</sub>	DC input impedance	—	40	50	60	Ω
Z <sub>RX-HIGH-IMP-DC</sub>	Power-down DC input impedance	—	200K	—	—	Ω
RL <sub>RX-DIFF</sub>	Differential return loss	—	10	—	—	dB
RL <sub>RX-CM</sub>	Common mode return loss	—	6.0	—	—	dB

**Notes:**

1. Values are measured at 2.5 Gb/s.
2. Measured with external AC-coupling on the receiver.
3. Not in compliance with PCI Express 1.1 standard.

## 4. Pinout Information

### 4.1. Signal Descriptions

Signal Name	I/O	Description
<b>General Purpose</b>		
P[L/R] [Group Number]_[A/B/C/D]	I/O	<p>[L/R] indicates the L (Left), or R (Right) edge of the device. [Group Number] indicates the PIO [A/B/C/D] group.</p> <p>[A/B/C/D] indicates the PIO within the PIC to which the pad is connected. Some of these user-programmable pins are shared with special function pins. These pins, when not used as special purpose pins, can be programmed as I/Os for user logic. During configuration the user-programmable I/Os are tristated with an internal pull-down resistor enabled. If any pin is not used (or not bonded to a package pin), it is tristated and default to have pull-down enabled after configuration.</p> <p>PIO A and B are grouped as a pair, and PIO C and D are group as a pair. Each pair supports true LVDS differential input buffer. Only PIO A and B pair supports true LVDS differential output buffer.</p> <p>Each A/B and C/D pair supports programmable on/off differential input termination of 100 <math>\Omega</math>.</p>
P[T/B][Group Number]_[A/B]	I/O	<p>[T/B] indicates the T (top) or B (bottom) edge of the device. [Group Number] indicates the PIO [A/B] group.</p> <p>[A/B] indicates the PIO within the PIC to which the pad is connected. Some of these user-programmable pins are shared with sysConfig pins. These pins, when not used as configuration pins, can be programmed as I/Os for user logic. During configuration, the pins not used in configuration are tristated with an internal pull-down resistor enabled. If any pin is not used (or not bonded to a package pin), it is tristated and default to have pull-down enabled after configuration.</p> <p>PIOs on top and bottom do not support differential input signaling or true LVDS output signaling, but it can support emulated differential output buffer.</p> <p>PIO A/B forms a pair of emulated differential output buffer.</p>
GSRN	I	Global RESET signal (active low). Any I/O pin can be GSRN.
NC	—	No connect.
RESERVED	—	This pin is reserved and should not be connected to anything on the board.
GND	—	Ground. Dedicated pins.
V <sub>CC</sub>	—	Power supply pins for core logic. Dedicated pins. V <sub>CC</sub> = 1.1 V (ECP5), 1.2 V (ECP5UM5G)
V <sub>CCAUX</sub>	—	Auxiliary power supply pin. This dedicated pin powers all the differential and referenced input buffers. V <sub>CCAUX</sub> = 2.5 V.
V <sub>CCIOx</sub>	—	Dedicated power supply pins for I/O bank x. V <sub>CCIO8</sub> is used for configuration and JTAG.
VREF1_x	—	Reference supply pins for I/O bank x. Pre-determined shared pin in each bank are assigned as VREF1 input. When not used, they may be used as I/O pins.
<b>PLL, DLL and Clock Functions</b>		
[LOC]_[GPLL[T, C]]_IN	I	General Purpose PLL (GPLL) input pads: [LOC] = ULC, LLC, URC and LRC, T = true and C = complement. These pins are shared I/O pins. When not configured as GPLL input pads, they can be used as general purpose I/O pins.
GR_PCLK[Bank][num]	I	General Routing Signals in Banks 0, 1, 2, 3, 4, 6 and 7. There are two in each bank ([num] = 0, 1). Refer to <a href="#">ECP5 sysClock PLL/DLL Design and Usage Guide (TN1263)</a> . These pins are shared I/O pins. When not configured as GR pins, they can be used as general purpose I/O pins.
PCLK[T/C][Bank]_[num]	I/O	General Purpose Primary CLK pads: [T/C] = True/Complement, [Bank] = (0, 1, 2, 3, 6 and 7). There are two in each bank ([num] = 0, 1). These are shared I/O pins. When not configured as PCLK pins, they can be used as general purpose I/O pins.

## 4.2. PICs and DDR Data (DQ) Pins Associated with the DDR Strobe (DQS) Pin

PICs Associated with DQS Strobe	PIO within PIC	DDR Strobe (DQS) and Data (DQ) Pins
For Left and Right Edges of the Device Only		
P[L/R] [n-6]	A	DQ
	B	DQ
	C	DQ
	D	DQ
P[L/R] [n-3]	A	DQ
	B	DQ
	C	DQ
	D	DQ
P[L/R] [n]	A	DQS (P)
	B	DQS (N)
	C	DQ
	D	DQ
P[L/R] [n+3]	A	DQ
	B	DQ
	C	DQ
	D	DQ

Note: "n" is a row PIC number.

## 4.3. Pin Information Summary

### 4.3.1. LFE5UM/LFE5UM5G

Pin Information Summary		LFE5UM/ LFE5UM5G-25		LFE5UM/LFE5UM5G-45			LFE5UM/LFE5UM5G-85			
Pin Type		285 csfBG	381 caBGA	285 csfBGA	381 caBG	554 caBGA	285 csfBGA	381 caBG	554 caBGA	756 caBGA
General Purpose Inputs/Outputs per Bank	Bank 0	6	24	6	27	32	6	27	32	56
	Bank 1	6	32	6	33	40	6	33	40	48
	Bank 2	21	32	21	32	32	21	34	32	48
	Bank 3	28	32	28	33	48	28	33	48	64
	Bank 4	0	0	0	0	0	0	0	14	24
	Bank 6	26	32	26	33	48	26	33	48	64
	Bank 7	18	32	18	32	32	18	32	32	48
	Bank 8	13	13	13	13	13	13	13	13	13
Total Single-Ended User I/O		118	197	118	203	245	118	205	259	365
VCC		13	20	13	20	24	13	20	24	36
VCCAUX (Core)		3	4	3	4	9	3	4	9	8
VCCIO	Bank 0	1	2	1	2	3	1	2	3	4
	Bank 1	1	2	1	2	3	1	2	3	4
	Bank 2	2	3	2	3	4	2	3	4	4
	Bank 3	2	3	2	3	3	2	3	3	4
	Bank 4	0	0	0	0	0	0	0	2	2
	Bank 6	2	3	2	3	4	2	3	4	4
	Bank 7	2	3	2	3	3	2	3	3	4
	Bank 8	2	2	2	2	2	2	2	2	2

## Supplemental Information

### For Further Information

A variety of technical notes for the ECP5/ECP5-5G family are available.

- [High-Speed PCB Design Considerations \(TN1033\)](#)
- [Transmission of High-Speed Serial Signals Over Common Cable Media \(TN1066\)](#)
- [PCB Layout Recommendations for BGA Packages \(TN1074\)](#)
- [Minimizing System Interruption During Configuration Using TransFR Technology \(TN1087\)](#)
- [Electrical Recommendations for Lattice SERDES \(FPGA-TN-02077\)](#)
- [LatticeECP3, ECP-5 and ECP5-5G Soft Error Detection \(SED\)/Correction \(SEC\) Usage Guide \(TN1184\)](#)
- [Using TraceID \(TN1207\)](#)
- [Sub-LVDS Signaling Using Lattice Devices \(TN1210\)](#)
- [Advanced Security Encryption Key Programming Guide for ECP5, ECP5-5G, LatticeECP3, and LatticeECP2/MS Devices \(TN1215\)](#)
- [LatticeECP3, LatticeECP2/M, ECP5 and ECP5-5G Dual Boot and Multiple Boot Feature \(TN1216\)](#)
- [ECP5 and ECP5-5G sysCONFIG Usage Guide \(TN1260\)](#)
- [ECP5 and ECP5-5G SERDES/PCS Usage Guide \(TN1261\)](#)
- [ECP5 and ECP5-5G sysIO Usage Guide \(TN1262\)](#)
- [ECP5 and ECP5-5G sysClock PLL/DLL Design and Usage Guide \(TN1263\)](#)
- [ECP5 and ECP5-5G Memory Usage Guide \(TN1264\)](#)
- [ECP5 and ECP5-5G High-Speed I/O Interface \(TN1265\)](#)
- [Power Consumption and Management for ECP5 and ECP5-5G Devices \(TN1266\)](#)
- [ECP5 and ECP5-5G sysDSP Usage Guide \(TN1267\)](#)
- [ECP5 and ECP5-5G Hardware Checklist \(FPGA-TN-02038\)](#)
- [Solder Reflow Guide for Surface Mount Devices \(FPGA-TN-02041\)](#)
- [ECP5 and ECP5-5G PCI Express Soft IP Ease of Use Guidelines \(FPGA-TN-02045\)](#)
- [Programming External SPI Flash through JTAG for ECP5/ECP5-5G \(FPGA-TN-02050\)](#)
- [Adding Scalable Power and Thermal Management to ECP5 Using L-ASC10 \(AN6095\)](#)

For further information on interface standards refer to the following websites:

- JEDEC Standards (LVTTTL, LVCMOS, SSTL): [www.jedec.org](http://www.jedec.org)
- PCI: [www.pcisig.com](http://www.pcisig.com)

(Continued)

Date	Version	Section	Change Summary
August 2014	1.2	DC and Switching Characteristics	SERDES High-Speed Data Receiver section. Updated Table 3.26. Serial Input Data Specifications, Table 3.28. Receiver Total Jitter Tolerance Specification, and Table 3.29. External Reference Clock Specification (refclkp/refclk).
			Modified section heading to XXAU/CPRI LV E.30 Electrical and Timing Characteristics. Updated Table 3.33 Transmit and Table 3.34. Receive and Jitter Tolerance.
			Modified section heading to CPRI LV E.24 Electrical and Timing Characteristics. Updated Table 3.35. Transmit and Table 3.36. Receive and Jitter Tolerance.
			Modified section heading to Gigabit Ethernet/SGMII/CPRI LV E.12 Electrical and Timing Characteristics. Updated Table 3.37. Transmit and Table 3.38. Receive and Jitter Tolerance.
June 2014	1.1	Ordering Information	Updated ECP5/ECP5-5G Part Number Description and Ordering Part Numbers sections.
March 2014	1.0	All	Initial release.